



Features

- 128K x 36 or 256K x 18 Organizations
- CMOS Technology
- Synchronous Flow-Thru Mode Of Operation with Self-Timed Late Write
- Dual Differential Input and Output Clocks
- +3.3V Power Supply, V_{DDQ} , V_{REF} & Ground
- HSTL Input and Output levels
- Registered Addresses, Write Enables, Sync Select and Data Ins
- Common I/O
- Asynchronous Output Enable and Power Down Inputs
- Boundary Scan using limited set of JTAG 1149.1 functions
- Byte Write Capability & Global Write Enable
- 7 X 17 Bump Ball Grid Array Package with SRAM JEDEC Standard Pinout and Boundary SCAN Order
- Programmable Impedance Output Drivers

Description

The IBM041840QLAA and IBM043640QLAA 4Mb SRAMs are Synchronous Flow-Thru Mode, high performance CMOS Static Random Access Memories that are versatile, wide I/O, and achieve 4.5 nsec cycle times. Dual differential K clocks are used to initiate the read/write operation and all internal operations are self-timed. At the rising edge of the K Clock, all Addresses, Write-Enables, Sync Select

and Data Ins are registered internally. Differential clocks C and \bar{C} are used to control the Output Data hold time by allowing output data to change after the rising edge of the C clock. An internal Write buffer allows write data to follow one cycle after addresses and controls. The chip is operated with a single +3.3V power supply and is compatible with HSTL I/O interfaces.

X36 BGA Bump Layout (Top View)

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 |
|---|------------------|-----------------|-------------------|-----------------|-------------------|-----------------|------------------|
| A | V _{DDQ} | SA5 | SA7 | NC | SA16 | SA14 | V _{DDQ} |
| B | NC | NC | SA8 | NC | SA11 | NC | NC |
| C | NC | SA6 | SA9 | V _{DD} | SA10 | SA15 | NC |
| D | DQc18 | DQc19 | V _{SS} | ZQ | V _{SS} | DQb10 | DQb9 |
| E | DQc20 | DQc21 | V _{SS} | \overline{SS} | V _{SS} | DQb12 | DQb11 |
| F | V _{DDQ} | DQc22 | V _{SS} | \overline{G} | V _{SS} | DQb13 | V _{DDQ} |
| G | DQc23 | DQc24 | \overline{SBWc} | \overline{C} | \overline{SBWb} | DQb15 | DQb14 |
| H | DQc25 | DQc26 | V _{SS} | C | V _{SS} | DQb17 | DQb16 |
| J | V _{DDQ} | V _{DD} | V _{REF} | V _{DD} | V _{REF} | V _{DD} | V _{DDQ} |
| K | DQd34 | DQd35 | V _{SS} | K | V _{SS} | DQa8 | DQa7 |
| L | DQd32 | DQd33 | \overline{SBWd} | \overline{K} | \overline{SBWa} | DQa6 | DQa5 |
| M | V _{DDQ} | DQd31 | V _{SS} | \overline{SW} | V _{SS} | DQa4 | V _{DDQ} |
| N | DQd29 | DQd30 | V _{SS} | SA0 | V _{SS} | DQa3 | DQa2 |
| P | DQd27 | DQd28 | V _{SS} | SA1 | V _{SS} | DQa1 | DQa0 |
| R | NC | SA4 | M1* | V _{DD} | M2* | SA12 | NC |
| T | NC | NC | SA3 | SA2 | SA13 | NC | ZZ |
| U | V _{DDQ} | TMS | TDI | TCK | TDO | NC | V _{DDQ} |

Note: * M1 and M2 are clock mode pins. For this application, M1 and M2 need to connect to V_{DD} and V_{DD}, respectively.

X18 BGA Bump Layout (Top View)

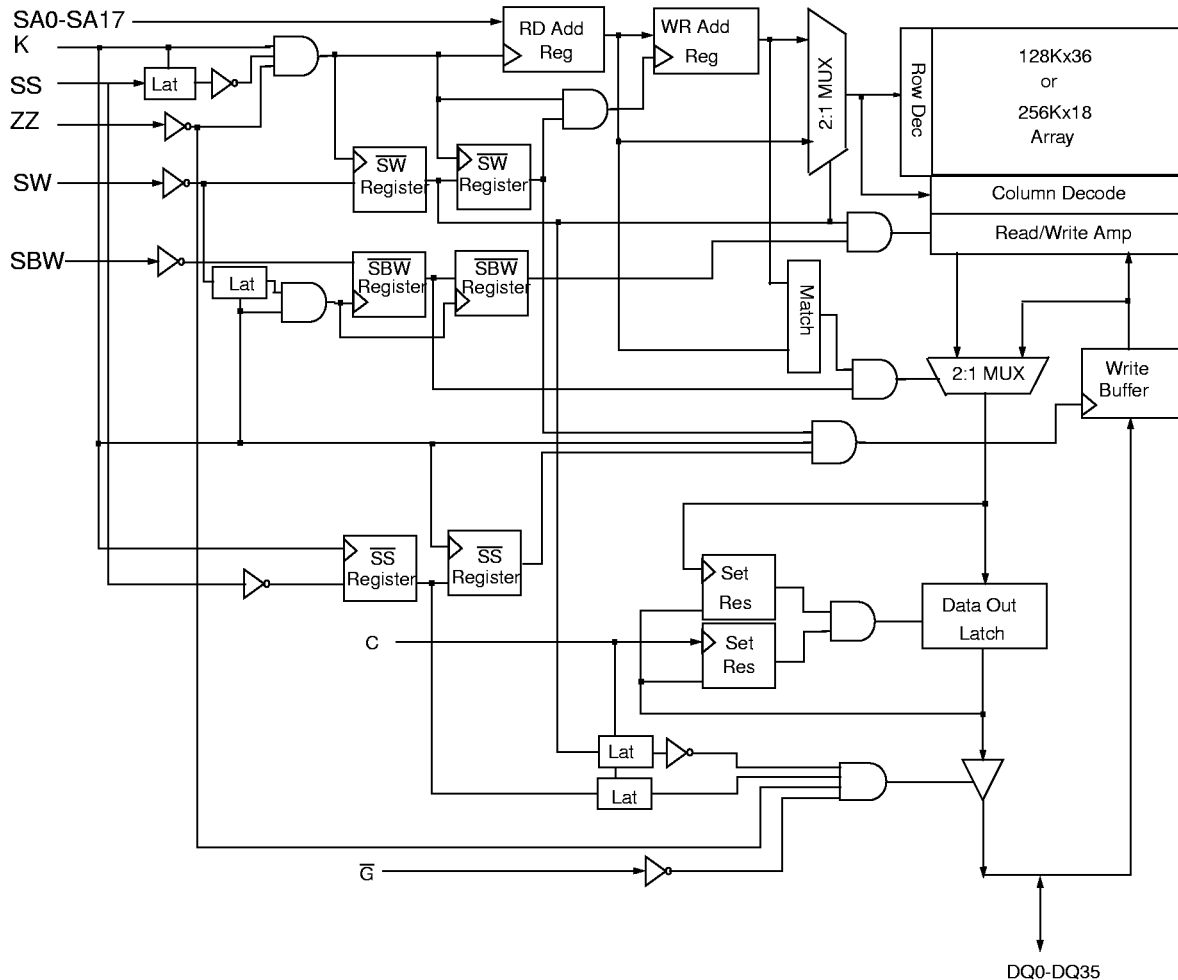
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 |
|---|------------------|-----------------|-------------------|-----------------|-------------------|-----------------|------------------|
| A | V _{DDQ} | SA5 | SA7 | NC | SA16 | SA14 | V _{DDQ} |
| B | NC | NC | SA8 | NC | SA11 | NC | NC |
| C | NC | SA6 | SA9 | V _{DD} | SA10 | SA15 | NC |
| D | DQb9 | NC | V _{SS} | ZQ | V _{SS} | DQa1 | NC |
| E | NC | DQb12 | V _{SS} | \overline{SS} | V _{SS} | NC | DQa2 |
| F | V _{DDQ} | NC | V _{SS} | \overline{G} | V _{SS} | DQa4 | V _{DDQ} |
| G | NC | DQb15 | \overline{SBWb} | \overline{C} | V _{SS} | NC | DQa5 |
| H | DQb16 | NC | V _{SS} | C | V _{SS} | DQa8 | NC |
| J | V _{DDQ} | V _{DD} | V _{REF} | V _{DD} | V _{REF} | V _{DD} | V _{DDQ} |
| K | NC | DQb17 | V _{SS} | K | V _{SS} | NC | DQa7 |
| L | DQb14 | NC | V _{SS} | \overline{K} | \overline{SBWa} | DQa6 | NC |
| M | V _{DDQ} | DQb13 | V _{SS} | \overline{SW} | V _{SS} | NC | V _{DDQ} |
| N | DQb11 | NC | V _{SS} | SA0 | V _{SS} | DQa3 | NC |
| P | NC | DQb10 | V _{SS} | SA1 | V _{SS} | NC | DQa0 |
| R | NC | SA4 | M1 | V _{DD} | M2 | SA13 | NC |
| T | NC | SA2 | SA3 | NC | SA17 | SA12 | ZZ |
| U | V _{DDQ} | TMS | TDI | TCK | TDO | NC | V _{DDQ} |

Note: * M1 and M2 are clock mode pins. For this application, M1 and M2 need to connect to V_{DD} and V_{DD} respectively.

Pin Description

| | | | |
|---------------|--|--------------|---|
| SA0-SA15 | Address Input | \bar{G} | Asynchronous Output Enable |
| DQ0-DQ35 | Data I/O | \bar{SS} | Synchronous Select |
| K, \bar{K} | Differential Input Register Clocks | M1, M2 | Clock Mode Inputs - Selects Single or Dual Clock Operation. |
| C, \bar{C} | Differential Output Data Hold Control Clocks | $V_{REF(2)}$ | GTL/HSTL Input Reference Voltage |
| \bar{SW} | Write Enable, Global | V_{DD} | Power Supply (+3.3V) |
| \bar{SBW}_a | Write Enable, Byte a (DQ0-DQ8) | V_{SS} | Ground |
| \bar{SBW}_b | Write Enable, Byte b (DQ9-DQ17) | V_{DDQ} | Output Power Supply |
| \bar{SBW}_c | Write Enable, Byte c (DQ18-DQ26) | ZZ | Asynchronous Sleep Mode |
| \bar{SBW}_d | Write Enable, Byte d (DQ27-DQ35) | ZQ | Output Driver Impedance Control |
| TMS,TDI,TCK | IEEE 1149.1 Test Inputs (LVTTTL levels) | NC | No Connect |
| TDO | IEEE 1149.1 Test Output (LVTTTL level) | | |

Block Diagram



SRAM FEATURES

Late Write

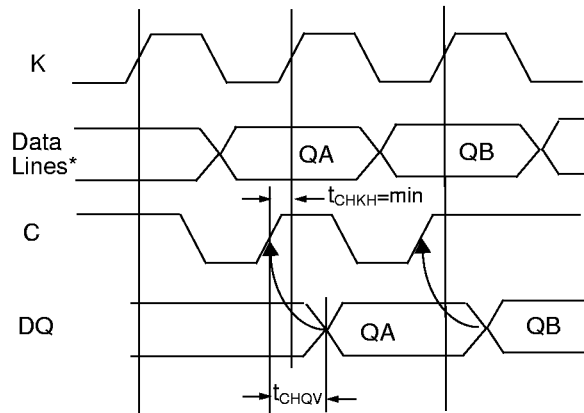
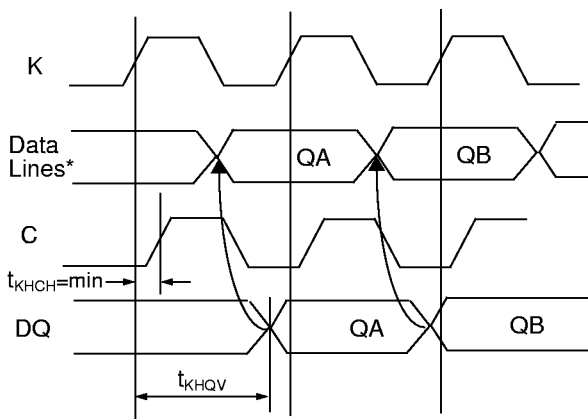
Late Write function allows for write data to be registered one cycle after addresses and controls. This feature will alleviate SRAM data bus contention going from a Read to Write cycle by eliminating one dead cycle. Late Write is accomplished by buffering write addresses and data so that the write operation occurs during the next write cycle. In the case a read cycle occurs after a write cycle, the address and write data information are stored temporarily in holding registers. During the first write cycle preceded by a read cycle, the SRAM array will be updated with address and data in the holding registers. Read cycle addresses are monitored to determine if read data is to be supplied from the SRAM array or the write buffer. The bypassing of the SRAM array occurs on a byte by byte basis. When one byte is written during a write cycle, read data from the last written address will have new byte data from the write buffer and remaining bytes from the SRAM array.

Dual Clock Operation

In Dual Clock Operation, the K Clocks are used to register all synchronous inputs and start the SRAM operation. The C Clocks are used to control the output data timings. During Write ($\overline{SW}=L$) or Deselect ($\overline{SS}=H$) operations, the rising edge of C Clock triggers the time to High-Z. During Read operations the location of the rising edge of the C Clock will determine the output data valid placement by allowing SRAM output data to flow through after the rising edge. When the rising edge of the C Clock occurs early in a Read cycle (e.g. $t_{KHCH} = \text{Min.}$), data from the SRAM will become available at a t_{KHQV} time, as it would in a Flow-Through Read implementation (see Dual Clock Diagram #1 below). As the C Clock rising edge moves away from $t_{KHCH} = \text{Min.}$, towards a $t_{CHKH} = \text{Min.}$, of the next K Clock rising edge, the output data may become "gated" by the C Clock (see Dual Clock Diagram #2 below). The SRAM access time will then become referenced to the C Clock (i.e. t_{CHQV}). This feature allows SRAM users to fully control the output data hold time over voltage, temperature and process variations, and provide minimum output data latency.

Dual Clock Diagram #1: Output data becomes available as a result of internal data lines flowing through the output latch unrestrained by the C clock.

Dual Clock Diagram #2: Internal data lines await at the output latch for the rising edge of C clock. The C clock enables the output latch and allows output data to become available.



*Data Lines refer to internal data lines connecting to Data Output Latch See Block Diagram on page 3.

Mode Control

Mode control pins: M1 and M2 are used to select four different JEDEC standard read protocols. This SRAM supports both the Single Clock, Flow-Through ($M1 = V_{SS}$, $M2 = V_{SS}$) and Dual Clock Flow-Through protocols ($M1 = V_{DD}$, $M2 = V_{DD}$). This data sheet only describes Dual Clock Flow-Through functionality. Mode control



inputs must be set with power up and must not change during SRAM operation.

Power Down Mode

Power Down Mode or “Sleep” Mode is enabled by switching asynchronous signal ZZ High. When the SRAM is in Sleep mode, the outputs will go to a High-Z state and the SRAM will draw standby current. SRAM data will be preserved and a recovery time (t_{ZZR}) is required before the SRAM resumes to normal operation.

Programmable Impedance/Power Up Requirements

An external resistor, R_Q , must be connected between the ZQ pin on the SRAM and V_{SS} to allow for the SRAM to adjust its output driver impedance. The value of R_Q must be 5X the value of the intended line impedance driven by the SRAM. The allowable range of R_Q to guarantee impedance matching with a tolerance of 7.5% is between 175 Ω and 350 Ω . Periodic readjustment of the output driver impedance is necessary as the impedance is greatly affected by drifts in supply voltage and temperature. One evaluation occurs every 64 clock cycles and each evaluation may move the output driver impedance level only one step at a time towards the optimum level. The output driver has 32 discrete binary weighted steps. The impedance update of the output driver occurs when the SRAM is in High-Z. Write and Deselect operations will synchronously switch the SRAM into and out of High-Z, therefore, triggering an update. The user may choose to invoke asynchronous \bar{G} updates by providing a \bar{G} setup and hold about the K Clock to guarantee the proper update. There are no power up requirements for the SRAM; however, to guarantee optimum output driver impedance after power up, the SRAM needs 1024 clock cycles followed by a Low-Z to High-Z transition.

Ordering Information

| Part Number | Organization | Speed | Leads |
|-----------------|--------------|-----------------------------|------------|
| IBM041840QLAA-4 | 256K x 18 | 6.5ns Access / 4.5 ns Cycle | 7 X 17 BGA |
| IBM041840QLAA-5 | 256K x 18 | 7.0ns Access / 5ns Cycle | 7 X 17 BGA |
| IBM041840QLAA-6 | 256K x 18 | 7.5ns Access / 6ns Cycle | 7 X 17 BGA |
| IBM043640QLAA-4 | 128K x 36 | 6.5ns Access / 4.5 ns Cycle | 7 X 17 BGA |
| IBM043640QLAA-5 | 128K x 36 | 7.0ns Access / 5ns Cycle | 7 X 17 BGA |
| IBM043640QLAA-6 | 128K x 36 | 7.5ns Access / 6ns Cycle | 7 X 17 BGA |

Output Enable Truth Table

| Operation | \bar{G} | DQ |
|---------------------------|-----------|-----------------------|
| Read | L | D _{OUT} 0-35 |
| Read | H | High-Z |
| Sleep (ZZ=H) | X | High-Z |
| Write (\bar{SW} =L) | X | High-Z |
| Deselect (\bar{SS} =H) | X | High-Z |



Clock Truth Table

| K, C CLK | ZZ | \overline{SS} | \overline{SW} | \overline{SBWA} | \overline{SBWB} | \overline{SBWC} | \overline{SBWD} | DQ (n) | DQ (n+1) | Mode |
|----------|----|-----------------|-----------------|-------------------|-------------------|-------------------|-------------------|-----------------------|-----------------------|-----------------------|
| L→H | L | L | H | X | X | X | X | D _{OUT} 0-35 | X | Read Cycle All Bytes |
| L→H | L | L | L | L | H | H | H | High-Z | D _{IN} 0-8 | Write Cycle 1st Byte |
| L→H | L | L | L | H | L | H | H | High-Z | D _{IN} 9-17 | Write Cycle 2nd Byte |
| L→H | L | L | L | H | H | L | H | High-Z | D _{IN} 18-26 | Write Cycle 3rd Byte |
| L→H | L | L | L | H | H | H | L | High-Z | D _{IN} 27-35 | Write Cycle 4th Byte |
| L→H | L | L | L | L | L | L | L | High-Z | D _{IN} 0-35 | Write Cycle All Bytes |
| L→H | L | L | L | H | H | H | H | High-Z | High-Z | Abort Write Cycle |
| L→H | L | H | X | X | X | X | X | High-Z | X | Deselect Cycle |
| X | H | X | X | X | X | X | X | High-Z | High-Z | Sleep Mode |

Absolute Maximum Ratings

| Item | Symbol | Rating | Units | Notes |
|------------------------------|------------------|------------------------------|-------|-------|
| Power Supply Voltage | V _{DD} | -0.5 to 3.9 | V | 1 |
| Input Voltage | V _{IN} | -0.5 to V _{DD} +0.5 | V | 1 |
| Output Voltage | V _{OUT} | -0.5 to V _{DD} +0.5 | V | 1 |
| Operating Temperature | T _J | 0 to +110 | °C | 1 |
| Storage Temperature | T _{STG} | -55 to +125 | °C | 1 |
| Short Circuit Output Current | I _{OUT} | 25 | mA | 1 |

1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.



Preliminary

PBGA Thermal Characteristics

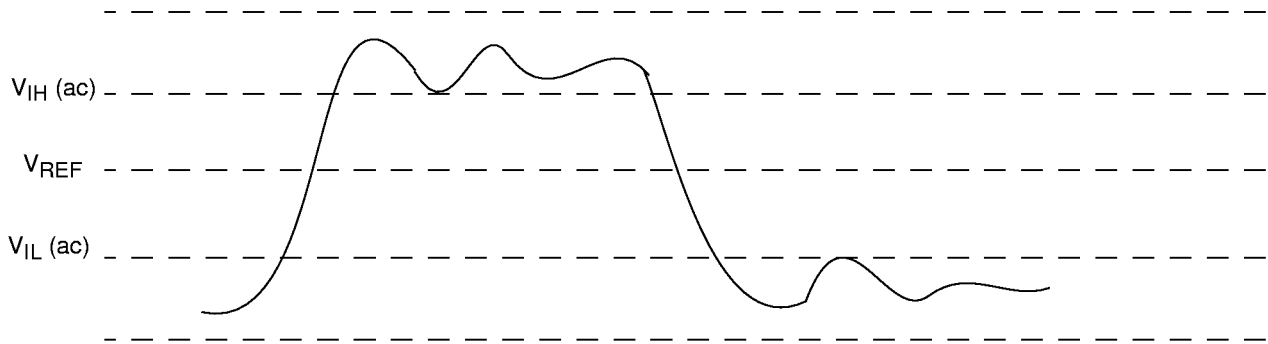
| Item | Symbol | Rating | Units |
|-------------------------------------|------------------|--------|-------|
| Thermal Resistance Junction to Case | R _{ΘJC} | 1 | °C/W |

AC Input Characteristics

| Item | Symbol | Min | Max | Notes |
|--|-----------------------|-----|--------------------------|-------|
| AC Input Logic High | V _{IH} (ac) | TBD | | 3 |
| AC Input Logic Low | V _{IL} (ac) | | TBD | 3 |
| Clock Input Differential Voltage | V _{DIF} (ac) | TBD | | 2 |
| V _{REF} Peak to Peak ac Voltage | V _{REF} (ac) | | 5% V _{REF} (dc) | 1 |

1. The peak to peak AC component superimposed on V_{REF} may not exceed 5% of the DC component of V_{REF}.
2. Performance is a function on V_{IH} and V_{IL} levels to clock inputs.
3. See AC Input Definition figure on page 7.

AC Input Definition



Recommended DC Operating Conditions (T_J=0 to 110°C)

| Parameter | Symbol | Min. | Typ. | Max. | Units | Notes |
|------------------------------------|----------------------|------------------------|------|------------------------|-------|-------|
| Supply Voltage | V _{DD} | 3.15 | 3.3 | 3.47 | V | 1 |
| Output Driver Supply Voltage | V _{DDQ} | 1.4 | 1.5 | 1.6 | V | 1 |
| Input High Voltage | V _{IH} | V _{REF} + 0.1 | — | V _{DDQ} + 0.3 | V | 1, 2 |
| Input Low Voltage | V _{IL} | -0.3 | — | V _{REF} - 0.1 | V | 1, 3 |
| Input Reference Voltage | V _{REF} | 0.68 | 0.75 | 0.90 | V | 1 |
| Clocks Signal Voltage | V _{IN-CLK} | -0.3 | — | V _{DDQ} + 0.3 | V | 1, 4 |
| Differential Clocks Signal Voltage | V _{DIF-CLK} | 0.1 | — | V _{DDQ} + 0.6 | V | 1, 5 |
| Clocks Common Mode Voltage | V _{CM-CLK} | 0.55 | — | 0.90 | V | 1 |
| Output Current | I _{OUT} | — | 5 | 8 | mA | |

1. All voltages referenced to V_{SS}. All V_{DD}, V_{DDQ} and V_{SS} pins must be connected.
 2. V_{IH}(Max)DC = V_{DDQ} + 0.3 V, V_{IH}(Max)AC = V_{DD} + 1.5 V (pulse width ≤ 4.0ns).
 3. V_{IL}(Min)DC = - 0.3 V, V_{IL}(Min)AC = - 1.5 V (pulse width ≤ 4.0ns).
 4. V_{IN-CLK} specifies the maximum allowable DC excursions of each differential clock (K, \bar{K} , C, \bar{C}).
 5. V_{DIF-CLK} specifies the minimum Clock differential voltage required for switching.

Capacitance (T_J=0 to 110°C, V_{DD}=3.3 -5% + 5% V, f=1MHz)

| Parameter | Symbol | Test Condition | Max | Units |
|---------------------------------|------------------|-----------------------|-----|-------|
| Input Capacitance | C _{IN} | V _{IN} = 0V | 3 | pF |
| Data I/O Capacitance (DQ0-DQ35) | C _{OUT} | V _{OUT} = 0V | 4 | pF |



Preliminary

DC Electrical Characteristics ($T_J = 0$ to $+110^\circ\text{C}$, $V_{DD} = 3.3 \pm 5\%$ V)

| Parameter | Symbol | Min. | Max. | Units | Notes |
|---|------------------------|----------------|---------------|---------------|-------|
| Average Power Supply Operating Current - X36 ($I_{OUT} = 0$, $V_{IN} = V_{IH}$ or V_{IL} , ZZ & $SS = V_{IL}$) | I_{DD5} I_{DD6} | — — | 650 575 | mA | 1 |
| Average Power Supply Operating Current - X18 ($I_{OUT} = 0$, $V_{IN} = V_{IH}$ or V_{IL} , ZZ & $SS = V_{IL}$) | I_{DD5} I_{DD6} | — — | 600 525 | mA | 1 |
| Power Supply Standby Current ($ZZ = V_{IH}$, All other inputs = V_{IH} or V_{IL} , $I_{OUT} = 0$) | I_{SBZZ} | — | 150 | mA | 1 |
| ($SS = V_{IH}$, $ZZ = V_{IL}$, All other inputs = V_{IH} or V_{IL} , $I_{OUT} = 0$) | I_{SBSS} | — | 200 | mA | 1 |
| Input Leakage Current, any input ($V_{IN} = V_{SS}$ or V_{DD}) | I_{LI} | — | +1 | μA | |
| Output Leakage Current ($V_{OUT} = V_{SS}$ or V_{DD} , DQ in High-Z) | I_{LO} | — | +1 | μA | |
| Output "High" Level Voltage ($I_{OH} = -6\text{mA}$ @ $V_{DDQ} / 2 + 0.3$) | V_{OH} | $V_{DDQ} - .4$ | V_{DDQ} | V | 2 |
| Output "Low" Level Voltage ($I_{OL} = +6\text{mA}$ @ $V_{DDQ} / 2 - 0.3$) | V_{OL} | V_{SS} | $V_{SS} + .4$ | V | 2 |

1. I_{OUT} = Chip Output Current.
2. Minimum Impedance Output Driver.

Programmable Impedance Output Driver DC Electrical Characteristics

($T_J = 0$ to $+110^\circ\text{C}$, $V_{DD} = 3.3 - 5\% + 5\%$ V)

| Parameter | Symbol | Min. | Max. | Units | Notes |
|-----------------------------|----------|---------------|---------------|-------|-------|
| Output "High" Level Voltage | V_{OH} | $V_{DDQ} / 2$ | V_{DDQ} | V | 1 |
| Output "Low" Level Voltage | V_{OL} | V_{SS} | $V_{DDQ} / 2$ | V | 2 |

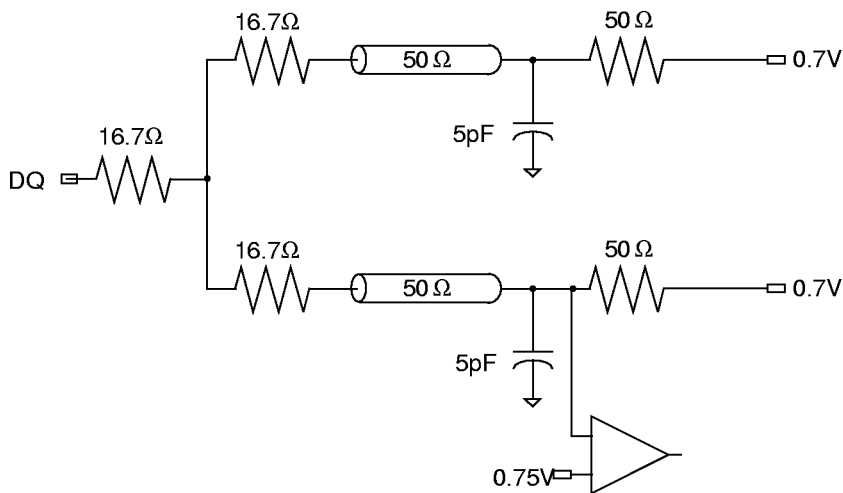
1. $I_{OH} = (V_{DDQ} / 2) / (RQ / 5)$ 7.5% @ $V_{OH} = V_{DDQ} / 2$ For: $150\Omega \leq RQ \leq 350\Omega$.
2. $I_{OL} = (V_{DDQ} / 2) / (RQ / 5)$ 7.5% @ $V_{OL} = V_{DDQ} / 2$ For: $150\Omega \leq RQ \leq 350\Omega$.

AC Test Conditions ($T_J=0$ to 110°C , $V_{DD}=3.3 - 5\% + 5\% V$, $V_{DDQ}+ 1.5V$)

| Parameter | Symbol | Conditions | Units | Notes |
|--|---------------|--------------------------|-------|-------|
| Input High Level | V_{IH} | 1.25 | V | |
| Input Low Level | V_{IL} | 0.25 | V | |
| Input Reference Voltage | V_{REF} | 0.75 | V | |
| Differential Clocks Voltage | $V_{DIF-CLK}$ | 0.75 | V | |
| Clocks Common Mode Voltage | V_{CM-CLK} | 0.75 | V | |
| Input Rise Time | T_R | 0.5 | ns | |
| Input Fall Time | T_F | 0.5 | ns | |
| I/O Signals Reference Level (except K, C Clocks) | | 0.75 | V | |
| Clocks Reference Level | | Differential Cross Point | V | |
| Output Load Conditions | | | | 1 |

1. See AC Test Loading figure on page 10.

AC Test Loading





AC Characteristics ($T_J=0$ to 110°C , $V_{DD}=3.3 - 5\% + 5\% V$)

| Parameter | Symbol | -4 | | -5 | | -6 | | Units | Notes |
|---------------------------------|-------------|------------|------|------------|------|------------|------|-------|---------|
| | | Min. | Max. | Min. | Max. | Min. | Max. | | |
| K Clock Cycle Time | t_{KHKH} | 4.5 | — | 5.0 | — | 6.0 | — | ns | |
| K Clock High Pulse Width | t_{KHKL} | 1.5 | — | 1.5 | — | 1.5 | — | ns | |
| K Clock Low Pulse Width | t_{KLKH} | 1.5 | — | 1.5 | — | 1.5 | — | ns | |
| C Clock Cycle Time | t_{CHCH} | t_{KHKH} | — | t_{KHKH} | — | t_{KHKH} | — | ns | |
| C Clock High Pulse Width | t_{CHCL} | 1.5 | — | 1.5 | — | 1.5 | — | ns | |
| C Clock Low Pulse Width | t_{CLCH} | 1.5 | — | 1.5 | — | 1.5 | — | ns | |
| K to C Clock Delay | t_{KHCH} | 1.5 | — | 1.5 | — | 1.5 | — | ns | |
| C to K Clock Delay | t_{CHKH} | 0.8 | — | 1.0 | — | 1.0 | — | ns | |
| K Clock to Output Valid | t_{KHQV} | — | 6.5 | — | 7.0 | — | 7.5 | ns | 1 |
| Data Out Hold Time from K Clock | t_{KHQX} | 2.0 | — | 2.5 | — | 3.0 | — | ns | 1, 2, 4 |
| K Clock High to Output Active | t_{KHQX4} | 2.5 | — | 3.0 | — | 3.5 | — | ns | 1, 2, 4 |
| C Clock to Output Valid | t_{CHQV} | — | 2.5 | — | 3.0 | — | 3.0 | ns | 1, 5 |
| Data Out Hold Time from C clock | t_{CHQX} | 0.5 | — | 0.5 | — | 0.5 | — | ns | 1, 2, 5 |
| C Clock High to Output High-Z | t_{CHQZ} | — | 2.5 | — | 3.0 | — | 3.0 | ns | 1, 2 |
| C Clock High to Output Active | t_{CHQX2} | 0.5 | — | 0.5 | — | 0.5 | — | ns | 1, 2, 5 |
| Address Setup Time | t_{AVKH} | 0.5 | — | 0.5 | — | 0.5 | — | ns | 6 |
| Address Hold Time | t_{KHAX} | 1.0 | — | 1.0 | — | 1.0 | — | ns | 6 |
| Synchronous Select Setup Time | t_{SVKH} | 0.5 | — | 0.5 | — | 0.5 | — | ns | 6 |
| Synchronous Select Hold Time | t_{KHSX} | 1.0 | — | 1.0 | — | 1.0 | — | ns | 6 |
| Write Enables Setup Time | t_{WVKH} | 0.5 | — | 0.5 | — | 0.5 | — | ns | 6 |
| Write Enables Hold Time | $t_{KH WX}$ | 1.0 | — | 1.0 | — | 1.0 | — | ns | 6 |
| Data In Setup Time | t_{DVKH} | 0.5 | — | 0.5 | — | 0.5 | — | ns | 6 |
| Data In Hold Time | t_{KHDX} | 1.0 | — | 1.0 | — | 1.0 | — | ns | 6 |
| Output Enable to Output Valid | t_{GLQV} | — | 2.4 | — | 2.5 | — | 3.0 | ns | 1 |
| Output Enable to Low-Z | t_{GLQX} | 0.5 | — | 0.5 | — | 0.5 | — | ns | 1, 2 |
| Output Enable to High-Z | t_{GHQZ} | — | 2.4 | — | 2.5 | — | 3.0 | ns | 1, 2 |
| Output Enable Set-up Time | t_{GHKH} | 0.5 | — | 0.5 | — | 0.5 | — | ns | 1, 3 |
| Output Enable Hold Time | t_{KHGX} | 1.5 | — | 1.5 | — | 1.5 | — | ns | 1, 3 |

1. See AC Test Loading figure on page 10.
2. Transitions are measured $\pm t_{bd}$ mV from steady state voltage.
3. Output Driver Impedance update specifications for \bar{G} induced updates. Write and Deselect cycles will also induce Output Driver updates during High-Z.
4. t_{KHQX} and t_{KHQX4} are used in instances where $t_{KHCH} = \text{Min.}$ and, therefore, the C Clock may not gate the output data.
5. t_{CHQV} , t_{CHQX} and t_{CHQX2} are used in instances where the output data is gated by the C Clock.
6. In use conditions V_{IH} , V_{IL} , T_{rise} , T_{fall} of inputs must be within 20% of V_{IH} , V_{IL} , T_{rise} , T_{fall} of Clocks.

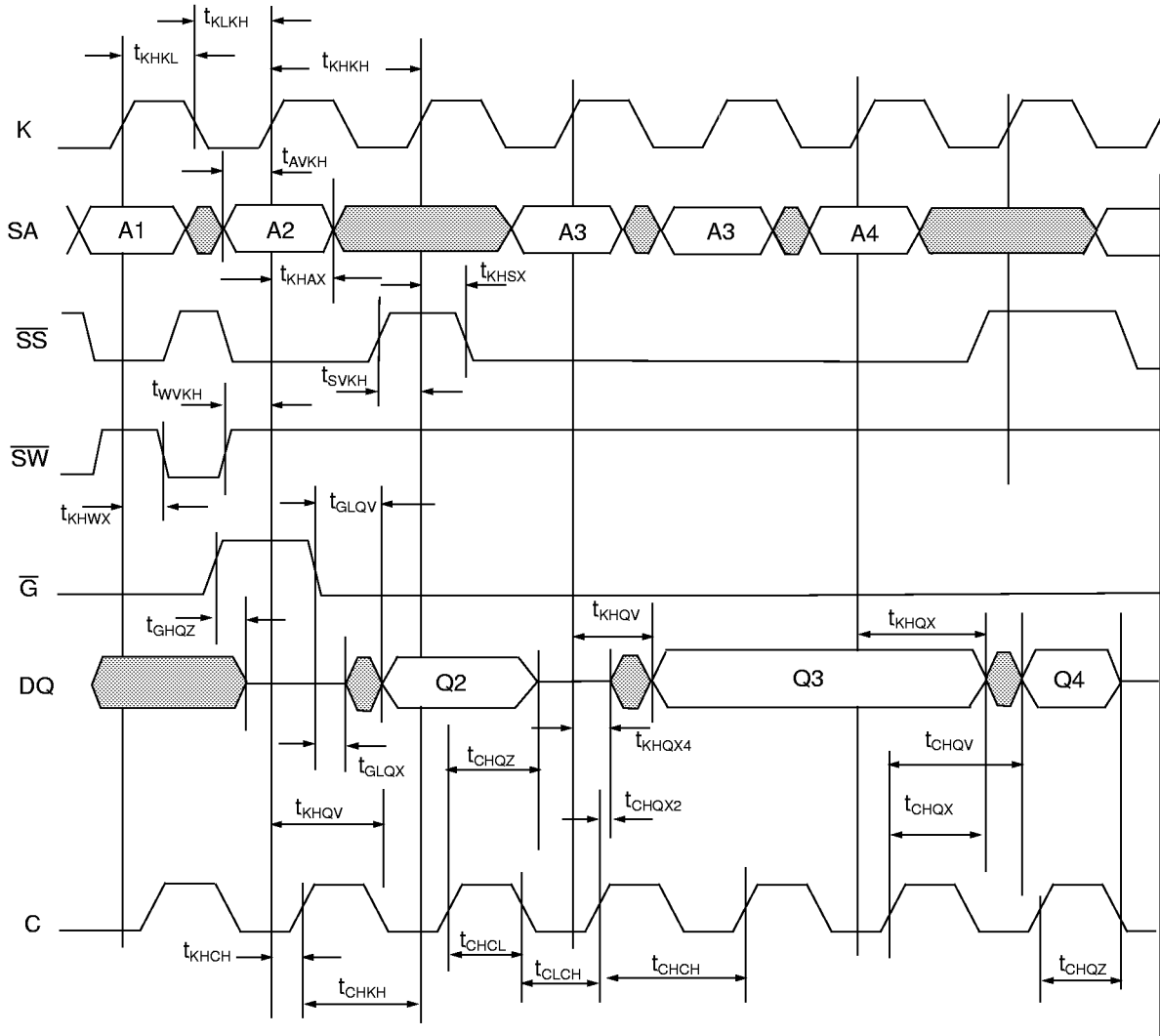


AC Characteristics ($T_J=0$ to 110°C , $V_{DD}=3.3 - 5\% + 5\% V$)

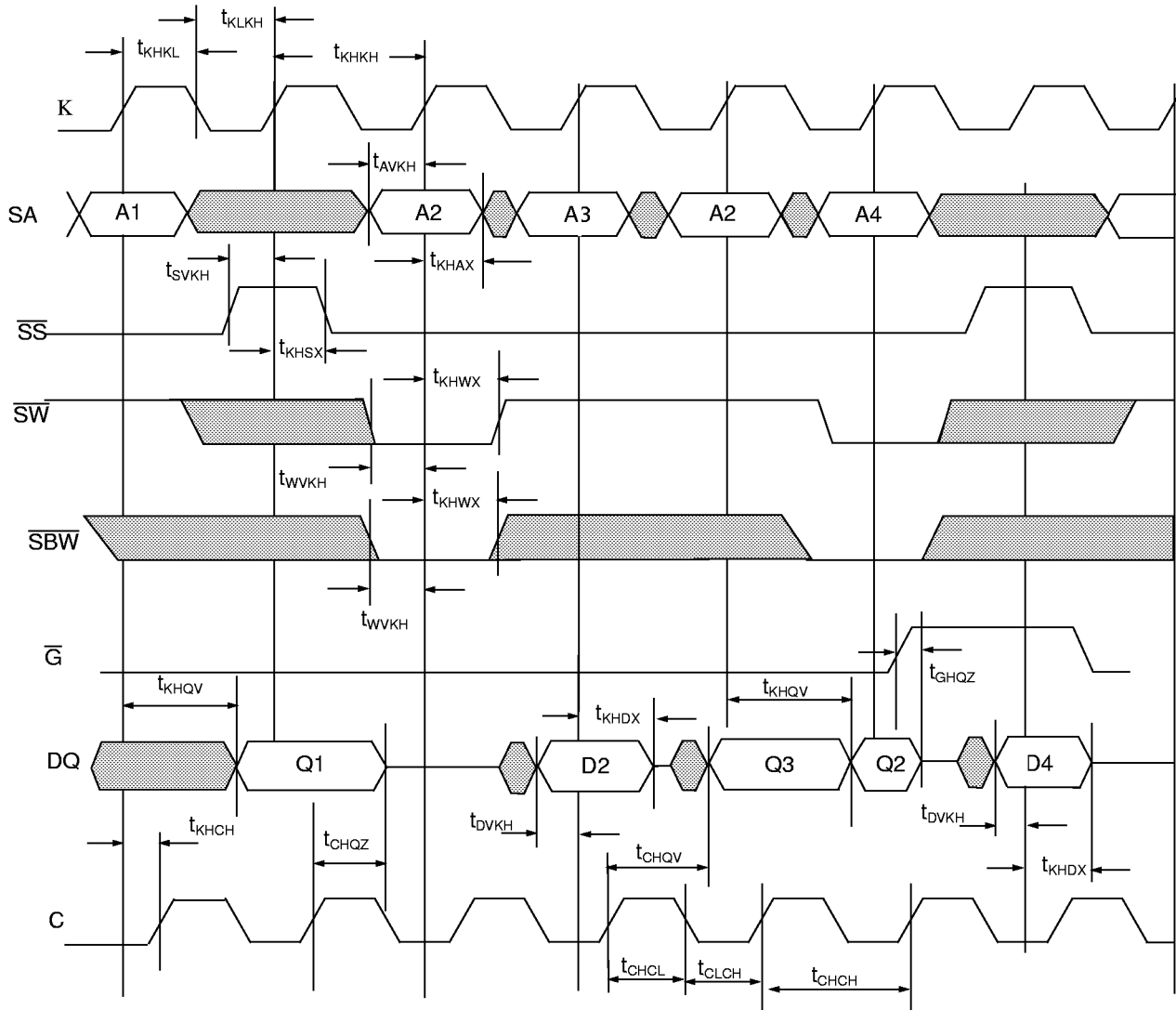
| Parameter | Symbol | -4 | | -5 | | -6 | | Units | Notes |
|--------------------------|-----------|------|------|------|------|------|------|-------|-------|
| | | Min. | Max. | Min. | Max. | Min. | Max. | | |
| Sleep Mode Recovery Time | t_{ZZR} | 4.5 | — | 5 | — | 6 | — | ns | |
| Sleep Mode Enable Time | t_{ZZE} | — | 4.5 | — | 5 | — | 6 | ns | |

1. See AC Test Loading figure on page 10.
2. Transitions are measured \pm tbd mV from steady state voltage.
3. Output Driver Impedance update specifications for \bar{G} induced updates. Write and Deselect cycles will also induce Output Driver updates during High-Z.
4. t_{KHQX} and t_{KHQX4} are used in instances where $t_{KHCH} = \text{Min.}$ and, therefore, the C Clock may not gate the output data.
5. t_{CHQV} , t_{CHQX} and t_{CHQX2} are used in instances where the output data is gated by the C Clock.
6. In use conditions V_{IH} , V_{IL} , T_{rise} , T_{fall} of inputs must be within 20% of V_{IH} , V_{IL} , T_{rise} , T_{fall} of Clocks.

Timing Diagram (Read and Deselect Cycles)



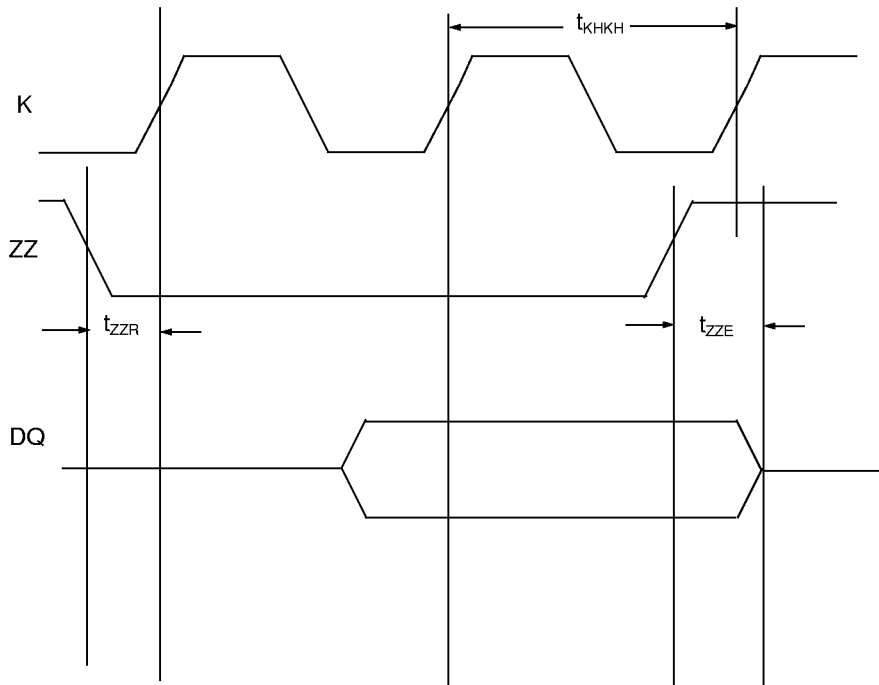
Timing Diagram (Read Followed by Write)



Notes:

1. D2 is the input data written in memory location A2.
2. Q2 is output data read from the write buffer, as a result of address A2 being a match from the last write cycle address.

Timing Diagram (Sleep Mode)



IEEE 1149.1 Tap And Boundary Scan

The SRAM provides a limited set of JTAG functions intended to test the interconnection between SRAM I/Os and printed circuit board traces or other components. There is no multiplexer in the path from I/O pins to the RAM core.

In conformance with IEEE std. 1149.1, the SRAMs contain a TAP controller, Instruction register, Boundary Scan register, Bypass register and ID register.

The TAP controller has a standard 16-state state machine that resets internally upon power-up, therefore, TRST signal is not required.

Signal List

- TCK: Test Clock
- TMS: Test Mode Select
- TDI: Test Data In
- TDO: Test Data Out

Caution: TCK, TMS, TDI inputs must be biased down, even if JTAG is not used.

JTAG Recommended DC Operating Conditions (T_J=0 to 110°C)

| Parameter | Symbol | Min. | Typ. | Max. | Units | Notes |
|-------------------------|------------------|------|------|----------------------|-------|-------|
| JTAG Input High Voltage | V _{IH1} | 2.2 | — | V _{DD} +0.3 | V | 1 |
| JTAG Input Low Voltage | V _{IL1} | -0.3 | — | 0.8 | V | 1 |
| JTAG Output High Level | V _{OH1} | 2.4 | — | — | V | 1, 2 |
| JTAG Output Low Level | V _{OL1} | — | — | 0.4 | V | 1, 3 |

1. All JTAG Inputs/Outputs are LVTTTL Compatible only.
 2. I_{OH1} = -8mA at 2.4V.
 3. I_{OL1} = +8mA at 0.4V.

JTAG AC Test Conditions (T_J=0 to 110°C, V_{DD}=3.3 -5% + 5% V)

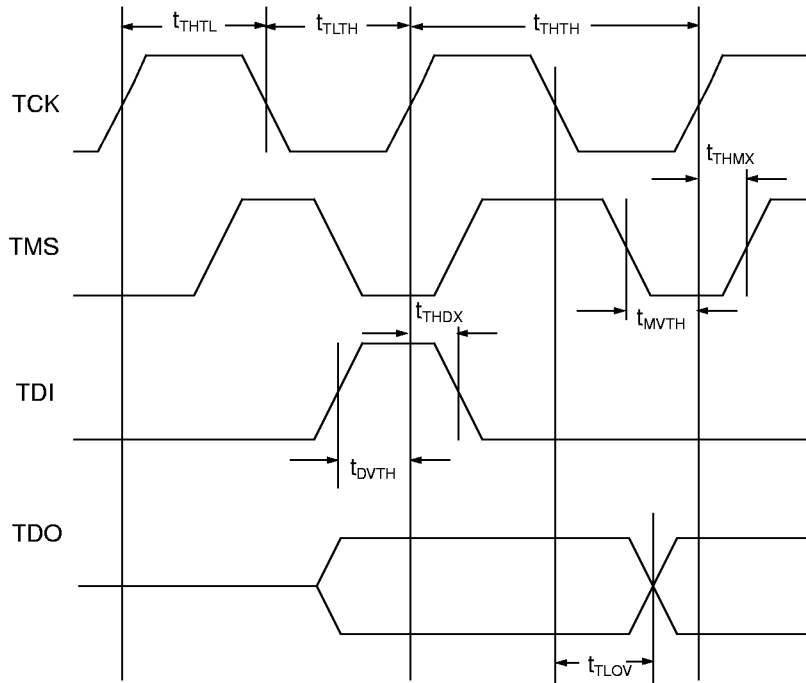
| Parameter | Symbol | Conditions | Units | Notes |
|---|------------------|------------|-------|-------|
| Input Pulse High Level | V _{IH1} | 3.0 | V | |
| Input Pulse Low Level | V _{IL1} | 0.0 | V | |
| Input Rise Time | T _{R1} | 2.0 | ns | |
| Input Fall Time | T _{F1} | 2.0 | ns | |
| Input and Output Timing Reference Level | | 1.5 | V | 1 |

1. See AC Test Loading figure on page 10.

JTAG AC Characteristics ($T_J=0$ to 110°C , $V_{DD}=3.3 -5\% + 5\% V$)

| Parameter | Symbol | Min. | Max. | Units | Notes |
|-----------------------|------------|------|------|-------|-------|
| TCK Cycle Time | t_{THTH} | 20 | — | ns | |
| TCK High Pulse Width | t_{THTL} | 7 | — | ns | |
| TCK Low Pulse Width | t_{TLTH} | 7 | — | ns | |
| TMS Setup | t_{MVTH} | 4 | — | ns | |
| TMS Hold | t_{THMX} | 4 | — | ns | |
| TDI Setup | t_{DVTH} | 4 | — | ns | |
| TDI Hold | t_{THDX} | 4 | — | ns | |
| TCK Low to Valid Data | t_{TLOV} | — | 7 | ns | 1 |

1. See AC Test Loading figure on page 10.

JTAG Timing Diagram




Scan Register Definition

| Register Name | Bit Size X18 | Bit Size X36 |
|-----------------|--------------|--------------|
| Instruction | 3 | 3 |
| Bypass | 1 | 1 |
| ID | 32 | 32 |
| Boundary Scan * | 51 | 70 |

- * The Boundary Scan chain consists of the following bits:
- 36 or 18 bits for Data Inputs Depending on X18 or X36 Configuration
 - 15 bits for SA0 - SA14 for X36, 16 bits for SA0 - SA15 for X18
 - 4 bits for SBW_a - SBW_d in X36, 2 bits for SBW_a and SBW_b in X18
 - 11 bits for K, \bar{K} , C, \bar{C} , ZQ, \bar{SS} , \bar{G} , \bar{SW} , ZZ, M1 and M2
 - 4 bits for Place Holders

* K, \bar{K} , C, \bar{C} clocks connect to a differential receiver that generates a single-ended clock signal. This signal and its inverted value are used for Boundary Scan sampling.

ID Register Definition

| Part | Field Bit Number and Description | | | | |
|----------|----------------------------------|--|---------------------------|-------------------------------|---------------|
| | Revision Number (31:28) | Device Density and Configuration (27:18) | Vendor Definition (17:12) | Manufacture JEDEC Code (11:1) | Start Bit (0) |
| 256K X18 | 0001 | 011 100 1011 | 001000 | 000 101 001 00 | 1 |
| 128K X36 | 0001 | 011 010 1100 | 001000 | 000 101 001 00 | 1 |

Instruction Set

| Code | Instruction | Notes |
|------|-------------|-------|
| 000 | SAMPLE-Z | 1, 5 |
| 001 | IDCODE | 2 |
| 010 | SAMPLE-Z | 1, 5 |
| 011 | PRIVATE | |
| 100 | SAMPLE | 4, 5 |
| 101 | PRIVATE | |
| 110 | PRIVATE | |
| 111 | BYPASS | 3 |

1. Places DQs in High-Z in order to sample all input data regardless of other SRAM inputs.
2. TDI is sampled as an input to the first ID register to allow for the serial shift of the external TDI data.
3. BYPASS register is initiated to VSS when BYPASS instruction is invoked. The BYPASS register also holds the last serially loaded TDI when exiting the Shift DR state.
4. SAMPLE instruction does not place DQs in High-Z.
5. SRAM must not be in Sleep mode (ZZ = H) when SAMPLE-Z or SAMPLE instructions are invoked.

List of IEEE 1149.1 standard violations:

- 7.2.1.b, e
- 7.7.1.a-f
- 10.1.1.b, e
- 10.7.1.a-d



Preliminary

IBM041840QLAA
 IBM043640QLAA
 128K X 36 & 256K X 18 SRAM

Boundary Scan Order (X36)

(PH =Place Holder)

| Exit Order | Signal | Bump # | Exit Order | Signal | Bump # | Exit Order | Signal | Bump # |
|------------|-------------------|--------|------------|--------|--------|------------|-------------------|--------|
| 1 | M2 | 5R | 25 | DQ13 | 6F | 49 | DQ26 | 2H |
| 2 | SA1 | 4P | 26 | DQ11 | 7E | 50 | DQ25 | 1H |
| 3 | SA2 | 4T | 27 | DQ12 | 6E | 51 | \overline{SBWc} | 3G |
| 4 | SA12 | 6R | 28 | DQ9 | 7D | 52 | ZQ | 4D |
| 5 | SA13 | 5T | 29 | DQ10 | 6D | 53 | \overline{SS} | 4E |
| 6 | ZZ | 7T | 30 | SA14 | 6A | 54 | \overline{C} | 4G |
| 7 | DQ1 | 6P | 31 | SA15 | 6C | 55 | C | 4H |
| 8 | DQ0 | 7P | 32 | SA10 | 5C | 56 | \overline{SW} | 4M |
| 9 | DQ3 | 6N | 33 | SA16 | 5A | 57 | \overline{SBWd} | 3L |
| 10 | DQ2 | 7N | 34 | PH* | 6B | 58 | DQ34 | 1K |
| 11 | DQ4 | 6M | 35 | SA11 | 5B | 59 | DQ35 | 2K |
| 12 | DQ6 | 6L | 36 | SA8 | 3B | 60 | DQ32 | 1L |
| 13 | DQ5 | 7L | 37 | PH* | 2B | 61 | DQ33 | 2L |
| 14 | DQ8 | 6K | 38 | SA7 | 3A | 62 | DQ31 | 2M |
| 15 | DQ7 | 7K | 39 | SA9 | 3C | 63 | DQ29 | 1N |
| 16 | \overline{SBWa} | 5L | 40 | SA6 | 2C | 64 | DQ30 | 2N |
| 17 | \overline{K} | 4L | 41 | SA5 | 2A | 65 | DQ27 | 1P |
| 18 | K | 4K | 42 | DQ19 | 2D | 66 | DQ28 | 2P |
| 19 | \overline{G} | 4F | 43 | DQ18 | 1D | 67 | SA3 | 3T |
| 20 | \overline{SBWb} | 5G | 44 | DQ21 | 2E | 68 | SA4 | 2R |
| 21 | DQ16 | 7H | 45 | DQ20 | 1E | 69 | SA0 | 4N |
| 22 | DQ17 | 6H | 46 | DQ22 | 2F | 70 | M1 | 3R |
| 23 | DQ14 | 7G | 47 | DQ24 | 2G | | | |
| 24 | DQ15 | 6G | 48 | DQ23 | 1G | | | |

1. * Input of PH register connected to V_{SS} .

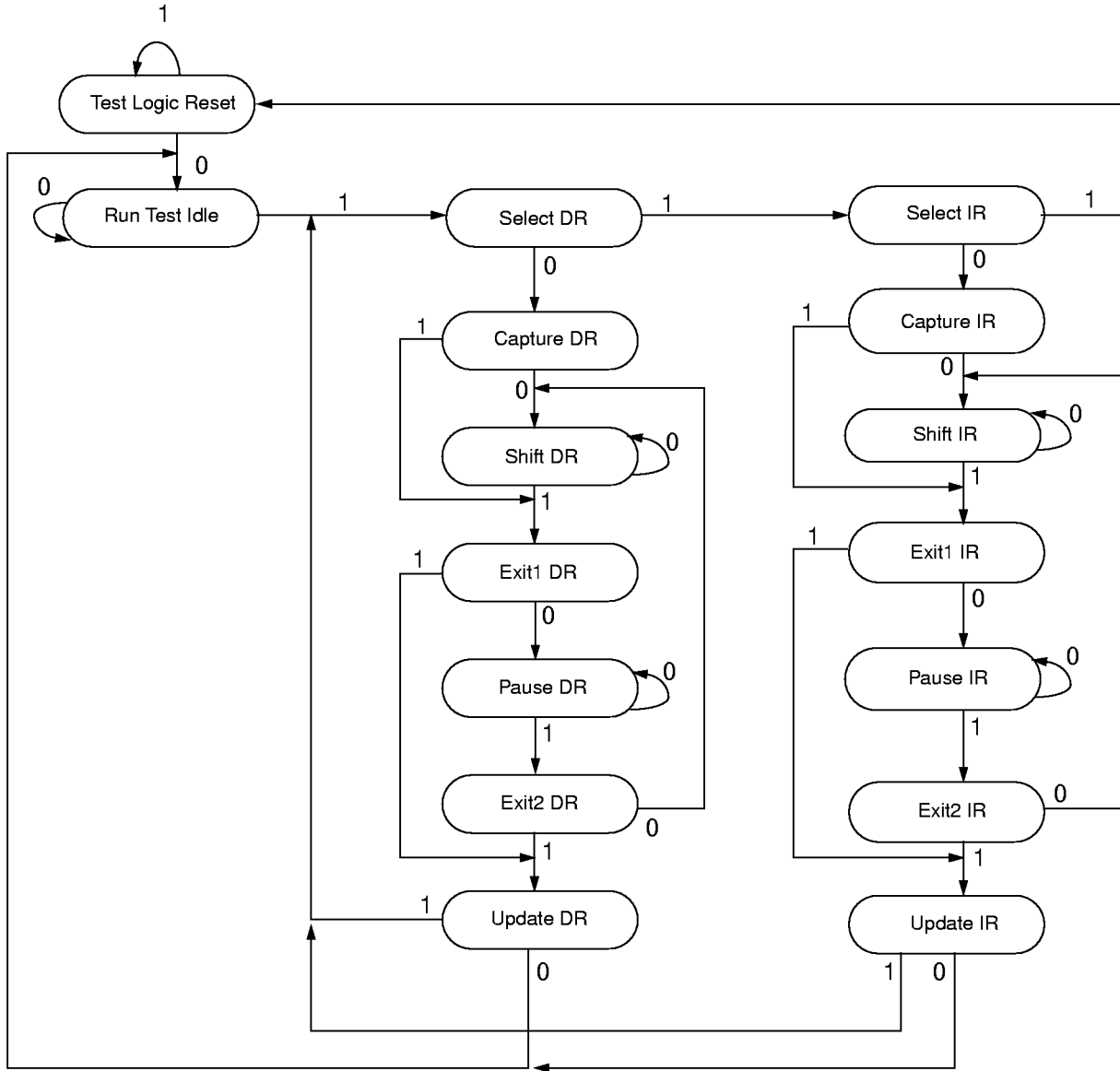
Boundary Scan Order (X18)

(PH =Place Holder)

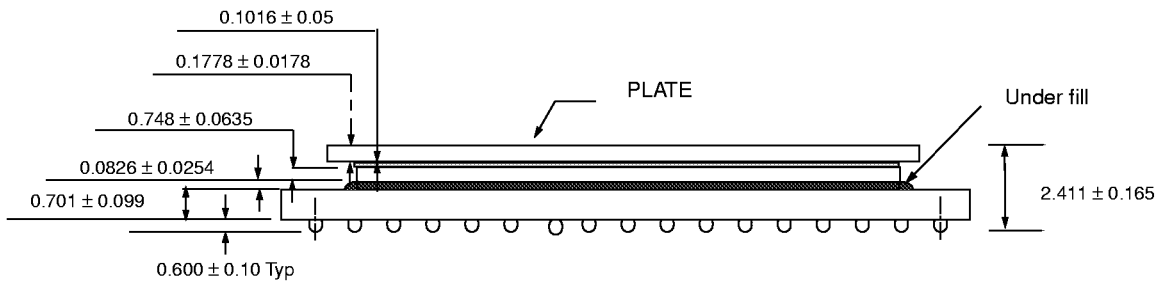
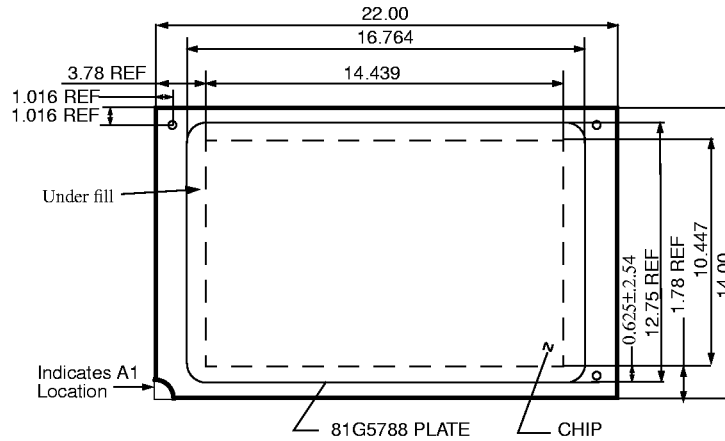
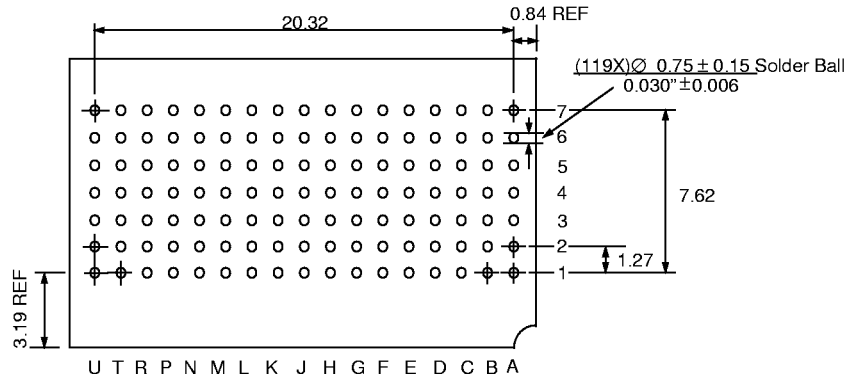
| Exit Order | Signal | Bump # | Exit Order | Signal | Bump # |
|------------|-----------|--------|------------|------------|--------|
| 1 | M2 | 5R | 27 | PH* | 2B |
| 2 | SA12 | 6T | 28 | SA7 | 3A |
| 3 | SA1 | 4P | 29 | SA9 | 3C |
| 4 | SA13 | 6R | 30 | SA6 | 2C |
| 5 | SA17 | 5T | 31 | SA5 | 2A |
| 6 | ZZ | 7T | 32 | DQ9 | 1D |
| 7 | DQ0 | 7P | 33 | DQ12 | 2E |
| 8 | DQ3 | 6N | 34 | DQ15 | 2G |
| 9 | DQ6 | 6L | 35 | DQ16 | 1H |
| 10 | DQ7 | 7K | 36 | SBWb | 3G |
| 11 | SBWa | 5L | 37 | ZQ | 4D |
| 12 | \bar{K} | 4L | 38 | \bar{SS} | 4E |
| 13 | K | 4K | 39 | \bar{C} | 4G |
| 14 | \bar{G} | 4F | 40 | C | 4H |
| 15 | DQ8 | 6H | 41 | \bar{SW} | 4M |
| 16 | DQ5 | 7G | 42 | DQ17 | 2K |
| 17 | DQ4 | 6F | 43 | DQ14 | 1L |
| 18 | DQ2 | 7E | 44 | DQ13 | 2M |
| 19 | DQ1 | 6D | 45 | DQ11 | 1N |
| 20 | SA14 | 6A | 46 | DQ10 | 2P |
| 21 | SA15 | 6C | 47 | SA3 | 3T |
| 22 | SA10 | 5C | 48 | SA4 | 2R |
| 23 | SA16 | 5A | 49 | SA0 | 4N |
| 24 | PH* | 6B | 50 | SA2 | 2T |
| 25 | SA11 | 5B | 51 | M1 | 3R |
| 26 | SA8 | 3B | | | |

1. * Input of PH register connected to V_{SS}.

TAP Controller State Machine



7 x 17 BGA Dimensions



Note: All dimensions in Millimeters